

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	8	(channel near region) and (substrate or wafer) and (soure or drain) and (deep near junction) and (shallow near3 region) and (silicon near oxide) and (impurity) and (gate near electrode) and (gate near dielectric).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/09 20:57
L2	18	(channel near region) and (substrate or wafer) and (soure or drain) and (deep near junction) and (shallow near3 region) and (silicon near oxide) and (impurity) and (gate near electrode) and (gate near dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/09 20:57